

## HW #3

Due October 16 (Tuesday) in class

1. Consider an infrared intersubband photodetector made of p-doped GaAs quantum wells. The hole effective mass is  $m_h^* = 0.5m_0$ , and the refractive index is 3.5.
  - a. Find the width of the quantum well so the absorption peak is at 10  $\mu\text{m}$  wavelength.
  - b. Assume a lorentzian lineshape with an intraband scattering time of 0.1 ps, find the peak absorption coefficient for a doping concentration of  $10^{18} \text{ cm}^{-3}$ .
  - c. What is the full-width-at-half-maximum width of the absorption spectrum?
  - d. Plot the absorption spectra. Please use your favorite numeric program to calculate and plot the spectrum (no hand sketch). Be quantitative in both axes.
  - e. What is the optimum doping concentration to achieve maximum absorption coefficient?
2. Consider an optical transition from  $E_a$  to  $E_b$  in a 10-nm wide GaAs single quantum well. Here,  $E_a$  and  $E_b$  are related by an optical transition (i.e., they have the same  $k$ ). Use the following effective masses:  $m_e^* = 0.067m_0$  and  $m_h^* = 0.5m_0$ . The bandgap energy of GaAs is 1.42 eV. Use infinite potential well for the calculation. Use the valence band edge as the reference for all energies (i.e.,  $E_V = 0 \text{ eV}$ ).
  - a. Find  $E_a$  and  $E_b$  as functions of the photon energy,  $\hbar\omega$ .
  - b. Derive the Fermi-Dirac distribution for electrons in the first conduction subband with a quasi-Fermi level of  $F_C$ ,  $f_C(E_b(\hbar\omega))$ , as a function of  $\hbar\omega$ .
  - c. Similarly, derive the Fermi-Dirac distribution for electrons in the first valence subband with a quasi-Fermi level of  $F_V$ ,  $f_V(E_a(\hbar\omega))$ , as a function of  $\hbar\omega$ .
  - d. Calculate and plot optical gain spectra for the GaAs quantum well for photon energy from 1.4 eV to 2 eV at  $T = 300 \text{ K}$ . Plot the spectra for two quasi Fermi level separations:  $\Delta F = 1.5$  and 1.8 eV. (Again, use your numeric program for calculation and plotting)
  - e. Calculate and plot the spontaneous emission spectra for the GaAs quantum well for photon energy from 1.4 eV to 2 eV at  $T = 300 \text{ K}$ . Plot the spectra for two quasi Fermi level separations:  $\Delta F = 1.5$  and 1.8 eV. (Again, use your numeric program for calculation and plotting)